



Features

- Unity gain stable
- Wide bandwidth—60 MHz
- High slew rate—200 V/µs
- High power bandwidth (±10 V_{out}) 3 MHz
- Large open loop gain 75 dB
- Low power—5 mA/amplifier
- Low input offset—1 mV typ.
- Wide supply voltage range $V_s = \pm 5V$ to $\pm 15V$
- Output short circuit protected

Applications

- High performance active filters
- Video and pulse amplifiers
- Local area networks
- Wideband amplifiers

Do

Ordering Information

Part No.	Temp. Range	Package	Outline #
EL2224CJ	0°C to +75°C	CerDIP	MDP0010
EL2224CN	0°C to +75°C	P-DIP	MDP0031
EL2224J	-55°C to +125°C	CerDIP	MDP0010
EL2224J/883B	- 55°C to + 125°C	CerDIP	MDP0010
EL2224L/883B	- 55°C to + 125°C	LCC	MDP0007
EL2224CM	0°C to +75°C	SOL	MDP0027

ELANTEC INC

General Description

L2224/EL2224C

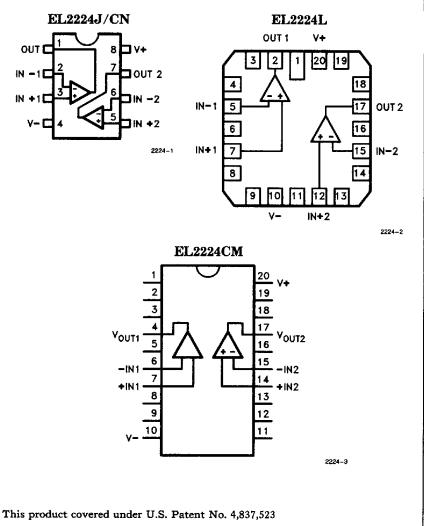
Dual, 60 MHz, Unity Gain Stable, Operational Amplifier

The EL2224 monolithic dual operational amplifier is an extension of Elantec's position in high speed analog products. This amplifier features unity gain stability, high slew rate and wide bandwidth, along with an excellent speed power relationship. The dual 60 MHz EL2224 consumes only 10 mA, making it ideal for video applications. The EL2224 has short circuit protected outputs and will operate from $\pm 5V$ to $\pm 15V$. It is fabricated using Elantec's Complementary Bipolar process which allows both fast PNP and NPN transistors to be manufactured on a single chip.

T-79.25

Elantec's products and facilities comply with MIL-STD-883 Revision C, MIL-I-45208A, and other applicable quality specifications. For information on Elantec's military processing, see Elantec document, QRA-2: "Elantec's Military Processing, Monolithic Integrated Circuits".

Connection Diagrams



July 1991 Rev

EL2224/EL2224C

1

ALJ 🖬 7129557 0002263 TJ7 📰 ELA 58E D



Do

EL2224/EL2224C ELANTEC INC Dual, 60 MHz, Unity Gain Stable, Operational Ampurier

Absolute Maximum Ratings $(T_A = 25^{\circ}C)$

Voltage Between V+ and V- Differential Input Voltage Internal Power Dissipation Peak Output Current Output Short Circuit Duration (Note 1)	35V ±6V See Curves Short Circuit Protected Continuous	Operational Temperature Range EL2224 EL2224C Storage Temperature Range Maximum Junction Temperature CerDIP, LCC	- 55°C to + 125°C 0°C to + 75°C - 65°C to + 150°C 175°C
		Plastic DIP, SOL	150°C
		Lead Temperature	2001
		DIP Package	300°C
		SOL Package	01.69.6
		Vapor Phase (60 seconds)	215°C
		Infrared (15 seconds)	220°C
performed during production and Q	uality inspection. Elantec perf	e Test Level column indicates the spec orms most electrical tests using modern noted, all tests are pulsed tests, theref	high-speed automatic test
Test Level Test Procedu	10		수 있는 것으로 가지 않는 것이다. 같은 이 이 것은 것으로 가지 않는 것이다.

	646				8 K G 10 I											
													n QC			
													r <u>a</u> =			
				TM												
	<u> </u>															
				OA												
	ा												riza			
													es op			

DC Electrical Characteristics $V_S = \pm 15V$; $R_L = 2 k\Omega$, unless otherwise specified

	Description			EL2224	1						
Parameter		Temp	Min	Тур	Max	Test Level	Min	Тур	Max	Test Level	Units
v _{os}	Offset Voltage	+ 25°C Full		0.5	5 8	1 1		0.5	5 8	I III	mV mV
TCVOS	Average Offset Voltage Drift	Full		20		v		20		v	μV/°C
IB	Bias Current	+ 25°C Full		1,5	4 6	I I		1.5	4 6	I III	μΑ μΑ
I _{OS}	Offset Current	+ 25°C Full		0.2	2 3	I I		0.2	2 3	I III	μΑ μΑ
R _{IN}	Input Resistance	+ 25°C		40		V		40		v	kΩ
C _{IN}	Input Capacitance	+ 25°C		1		v		1		v	pF
V _{CM}	Common Mode Input Range	Full	±10	±12		1	±10	±12		II	v
eIN	Input Noise Voltage (f = 1 kHz, R _G = 0Ω)	+25°C		15		v		15		v	nV/√Hz
A _{VOL}	Large Signal Voltage Gain (Notes 2, 3)	+ 25°C Full	4k 2.5k	6k		I	4k 2.5k	6k		I III	V/V V/V

■ 3129557 0002264 973 ■ ELA 58E D

EL2224/EL2224C Dual, 60 MHz, Unity Gain Stable, Operational Amplifier

DC Electrical Characteristics $V_{S} = \pm 15V$; $R_{L} = 2 k\Omega$, unless otherwise specified — Contd.

				EL2224							
Parameter	Description	Temp	Min	Тур	Max	Test Level	Min	Тур	Max	Test Level	Units
CMRR	Common-Mode Rejection Ratio (Note 4)	Full	70	80		I	60	80		п	dB
vo	Output Voltage Swing	Full	±11	±12.5		1	±11	±12.5		II	v
I _{SC}	Short Circuit Current	25°C		± 50	±70	T		± 50	± 70	1	mA
R _O	Output Resistance	25°C		40		v		40		v	Ω
Is	Supply Current	Full		9.5	13	1		9.5	13	II	mA
PSRR	Power Supply Rejection Ratio (Note 5)	Full	60	75		1		75		11	dB

AC Electrical Characteristics $V_S = \pm 15V$; $R_L = 2 k\Omega$, unless otherwise specified

				EL2224	Į						
Parameter	Description	Temp	Min	Тур	Max	Test Level	Min	Тур	Max	Test Level	Units
f _u	Open Loop Unity Bandwidth (Note 6)	25°C		60		v		60		v	MHz
FPBW	Full Power Bandwidth (Notes 2, 7)	25°C	2.4	3.1		1	2.4	3.1		I	MHz
t _r	Rise Time (Note 8)	25°C		6		v		6		v	ns
OS	Overshoot (Note 8)	25°C		20		v		20		v	%
SR	Slew Rate (Note 8)	25°C	150	200		1	150	200		1	V/µs
t _s	Settling Time (Notes 9, 10) 10V Step to 0.05%	25°C		120		V		120		v	ns
Ch S _p	Channel Separation (f = 10 MHz)	Full		70		v		70		V	dB

Note 1: A heat sink is required to keep the junction temperature below absolute maximum when the output is shorted.

Note 2: $V_0 = \pm 10V$.

Note 3: $\mathbf{R}_{\mathbf{L}} = 2 \mathbf{k} \Omega$.

Note 4: Two tests are performed. $V_{CM} = 0V$ to +10V and $V_{CM} = 0$ to -10V.

Note 5: Two tests are performed. V + = 15V, and V - is changed from -5V to -15V. V - = -15V, and V + is changed from +5Vto +15V.

Note 6: $V_0 = 100 \text{ mV}$.

Note 7: Full Power Bandwidth guaranteed based on slew rate measurement using: FPBW = Slew Rate/ 2 π V_{PEAK}.

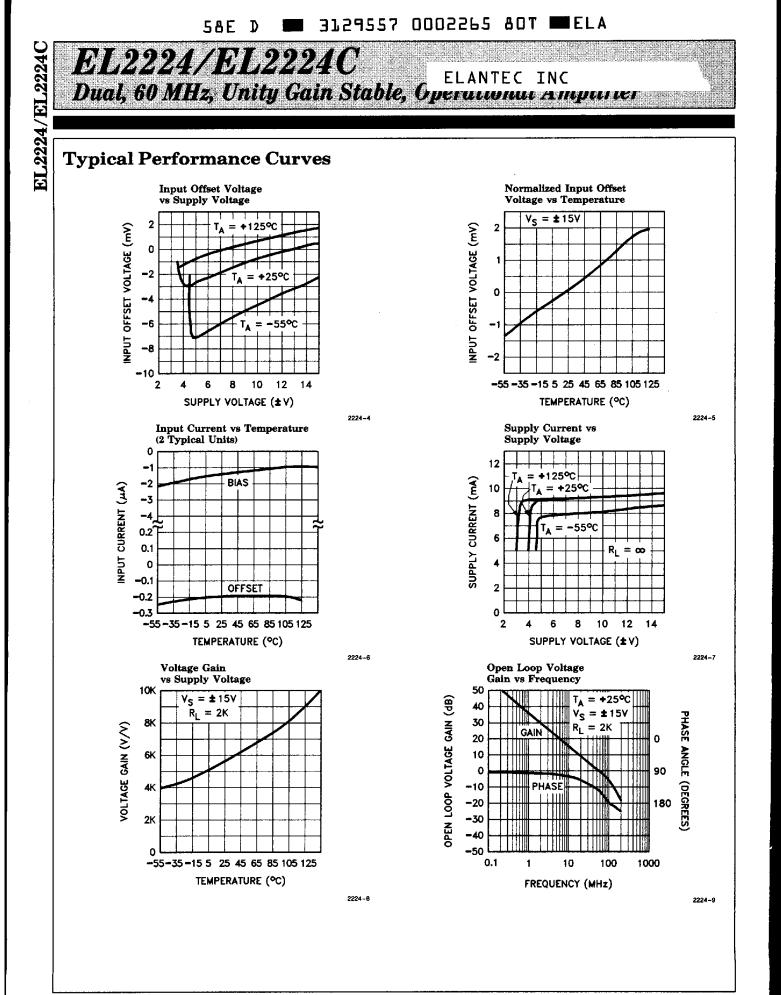
Note 8: Refer to Test Circuit section of data sheet.

ELANTEC INC

Note 9: Settling time measurement are made with techniques in the following reference: "Take The Guesswork Out of Settling-Time Measurements," EDN September 19, 1985.

Note 10: $A_V = + 1$, $R_L = 2 k\Omega$.

1



1-278

Do

3129557 0002266 746 🎟 ELA 58E D EL2224/EL2224C EL2224/EL2224C ELANTEC INC Dual, 60 MHz, Unity Gain Stable, Operational Amplifier Typical Performance Curves - Contd. Gain Bandwidth at 10 MHz Slew Rate vs vs Supply Voltage Supply Voltage Av +1= BANDWIDTH AT 10 MHz (MHz) = -55°C 200 T₄ 60 25 SLEW RATE (V/µs) 180 50 +125°C = 160 40 -55°C 140 30 RL = 2K= +1 ΑU 120 20 < 10 pF CL R_L = 2K + 100 10 GAIN 80 0 6 8 10 12 2 4 14 8 10 12 2 4 6 14 1 SUPPLY VOLTAGE (±V) SUPPLY VOLTAGE (±V) 2224-11 2224-10 Settling Time $A_V = +1$ **Output Voltage Swing** vs Frequency 28 OUTPUT VOLTAGE SWING (VOLTSp_p) = +25°C output voltage step (v_{p-p}) 8 ± 15 = 2K SUPPLY 24 10 mV 5 mV 20 4 $R_L = 2K$ C_L < 30 pF 16 0 = ±10\ $V_{S} = \pm 15V$ SUPPLY 12 -4 8 1111 10 mV 5 mV = ±5V -8 VSUPPLY 4 11100 0 40 120 160 10K 80 200 100K 1M 10M 100M SETTLING TIME (ns) FREQUENCY (Hz) 2224-13 2224-12 **Common Mode Rejection vs Power Supply Rejection** Frequency $A_V = +10$ **Ratio vs Frequency** 100 POWER SUPPLY REJECTION RATIO (dB) 80 = +25°C T₄ COMMON MODE REJECTION (dB) $T_A = +25^{\circ}C$ = ±15V $R_L = 2K$ ۷s 80 60 +10 = ٧s $= \pm 15$ 60 40

1-279

1000

2224-14

40

20

0

10K

100K

1 M

FREQUENCY (Hz)

10M

100M

2224-15

PSRR

SRE

1

10

FREQUENCY (MHz)

100

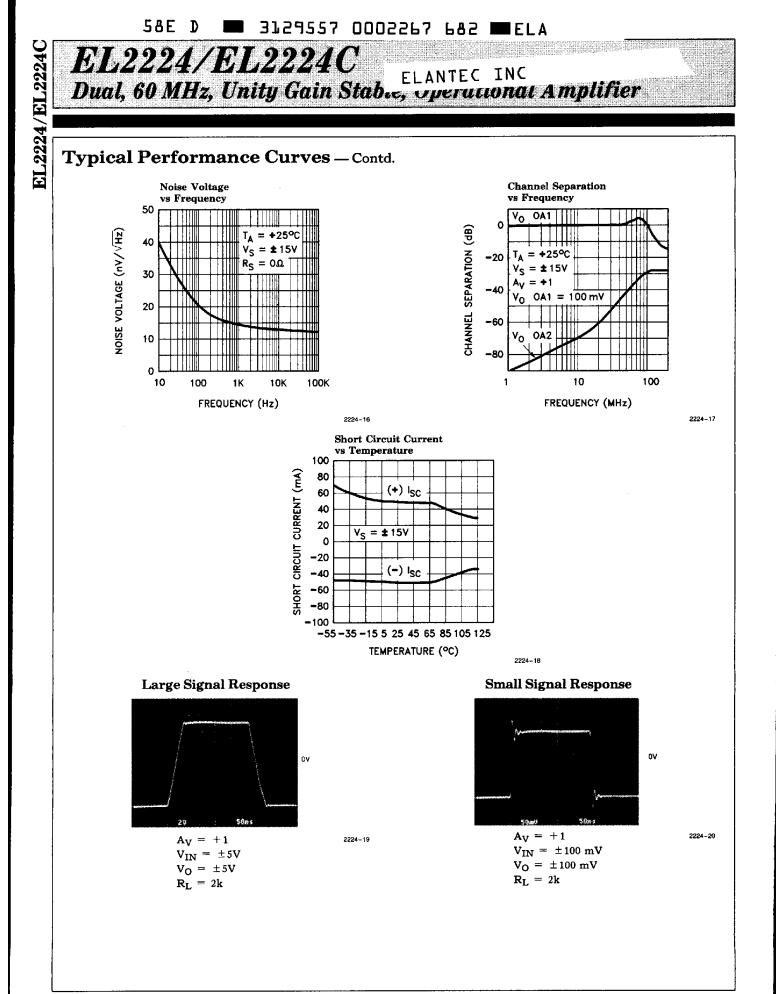
20

0

20

Do

0.1



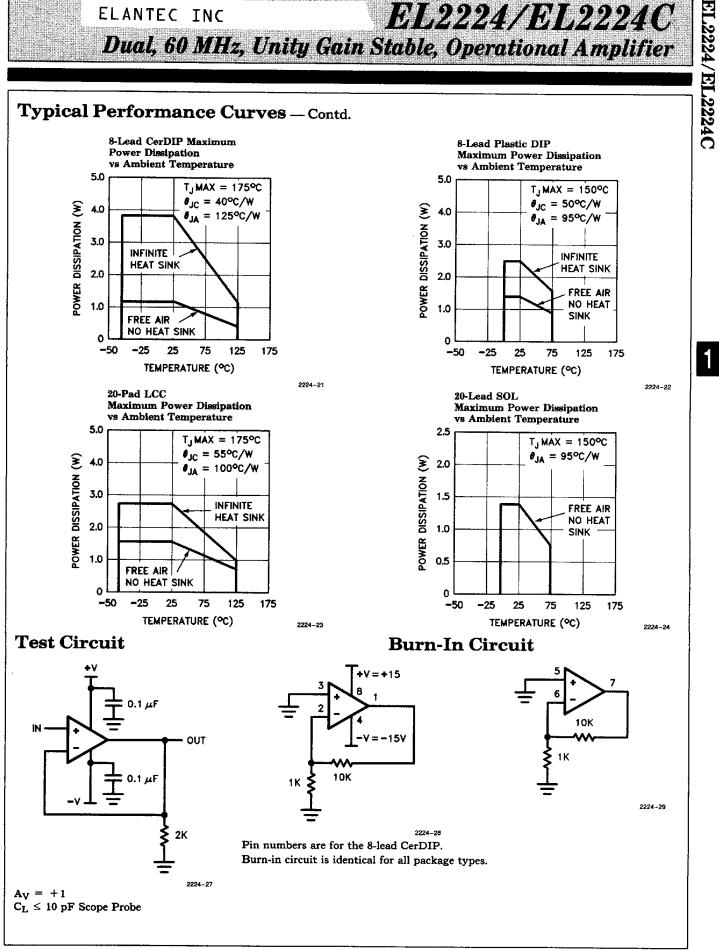
Do

anhosaledufron

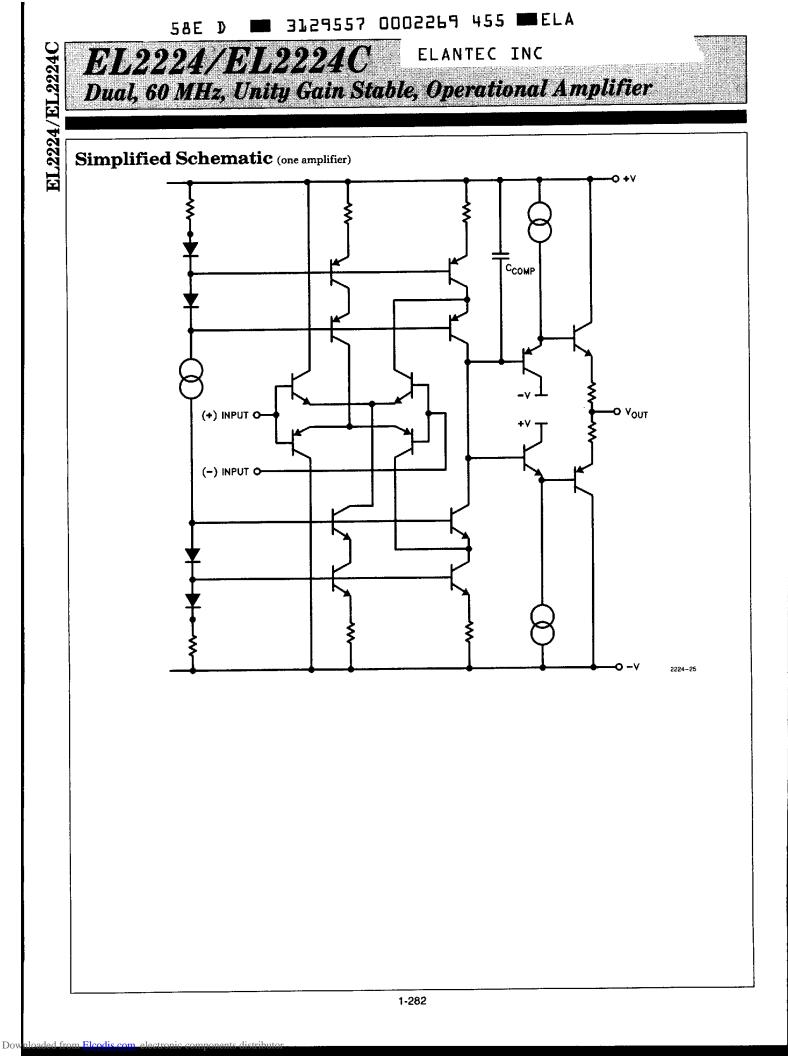
58E D ■ 3129557 0002268 519 ■ ELA

EL2224/EL2224C Dual, 60 MHz, Unity Gain Stable, Operational Amplifier

ELANTEC INC



Do



ELANTEC INC

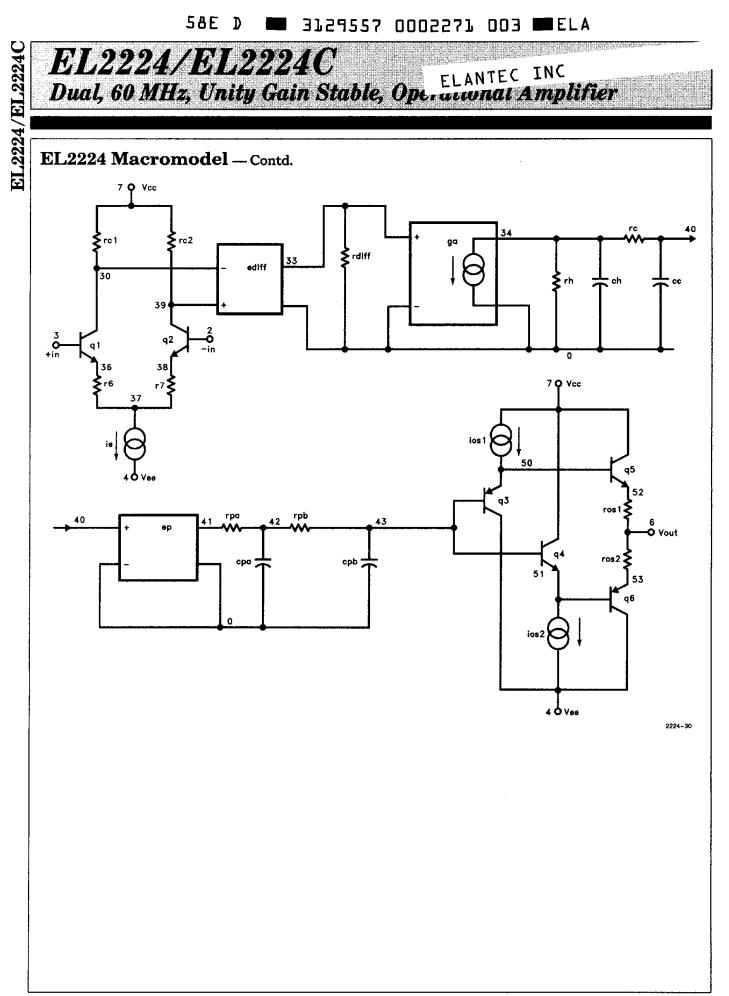
EL2224/EL2224C Dual, 60 MHz, Unity Gain Stable, Operational Amplifier

EL2224 Macromodel

* Commenting					
* Connections:	+ inp				
•		—ing			
•	1	1		upply	
*	ł	ļ	1	-Vs	upply
*			ł		output
*	ļ				
.subckt M2224	3	2	7	4	6
* Input stage					
ie 37 4 4.5mA					
r6 36 37 75					
r7 38 37 75					
rc1 7 30 75					
rc2 7 39 75					
q1 30 3 36 qn					
q2 39 2 38 qna					
ediff 33 0 39 30 2.6					
rdiff 33 0 1Meg					
* Compensation S	ection				
ga 0 34 33 0 3m					
rh 34 0 1Meg					
ch 34 0 15pF					
rc 34 40 300					
cc 40 0 1pF					
* Poles					
ep 41 0 40 0 1					
rpa 41 42 75					
сра 42 0 3рF					
rpb 42 43 50					
cpb 43 0 3pF					
* Output Stage					
ios1 7 50 0.5mA					
ios2 51 4 0.5mA					
q3 4 43 50 qp					
q4 7 43 51 qn					
q5 7 50 52 qn					
q6 4 51 53 qp					
ros1 52 6 25					
ros2 6 53 25					
* models					
.model qn npn(is=	- 800.0	E-18	bf = 3	50 tf =	0.2nS)
.model qna npn(is	= 8641	2-18	bf = 40	0 tf = 0).2nS)
.model qp pnp(is=	800E	— 18 b	f = 60 ·	tf = 0.2	nS)
.ends					

Do

1



Do

aded fro